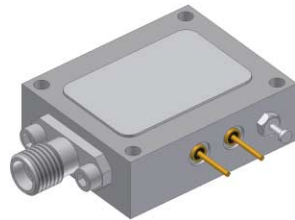




Agilent VTO-1990-SMA, VTO-2150-SMA Voltage Controlled Oscillator

Data Sheet

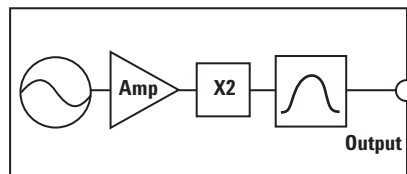


Description

The VTO-1990-SMA and VTO-2150-SMA provides a fundamental, low jitter source as a key component for the data re-timing in the transmitter subsystem and clock and data recovery in the receiver of the 40 Gb fiber optic systems.

The oscillator uses an extremely high performance low noise Agilent Silicon Bipolar transistor in conjunction with a hyperabrupt varactor diode to provide the tuning capability. The oscillator output is then coupled to an Agilent GaAs FET MMIC amplifier and MMIC multiplier chain to double the frequency. Finally the output is filtered through a bandpass filter prior to outputting the signal at 19.906 or 21.509 GHz.

Functional Block Diagram



Features

- Operating frequency: 19.906 or 21.509 GHz
- Output power (50Ω load): 3 dBm minimum
- Modulation sensitivity: 10 to 20 MHz/V
- Tuning voltage: 0 to 10 Volts
- Low jitter (Less than 50 femto seconds from 50 KHz to 80 MHz)
- Frequency drift over 0°C to +75°C: 40 MHz
- 1.180" x 0.950" x 0.400"
- 5 Volt bias optional

Applications

- Transmitter and receiver sub-systems for OC-768/STM-256 applications
- 20 GHz source

VTO-1990-SMA and VTO-2150-SMA Absolute Maximum Ratings^[1]

Parameter	Units	Ratings
Positive Supply Voltage	V	0 to +10
Tuning Voltage	V	0 to +12
Operating Temperature	°C	-10 to +95
Storage Temperature	°C	-40 to +130

Note:

1. Operation of this device in excess of any of these limits may cause permanent damage.



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VTO-1990-SMA & VTO-2150-SMA Summary Characterization, 0°C to 75°C

Parameter	Units	Min	Typ	Max
Frequency Range f_0	GHz		19.906 or 21.509	
Vt @ f_0 GHz	V	0		10
Power Output (50 Ω Load)	dBm	3		7
Modulation Sensitivity	MHz/V	10		20
Modulation Sensitivity Variation	%	-20		20
Modulation Bandwidth	MHz	100		
Output Return Loss	dB	10	12	
Second Harmonic (Below Carrier)	dBc			-20
Third Harmonic (Below Carrier)	dBc			-20
Sub Harmonically Related Spurious	dBc			-30
Spurious Output (Below Carrier)	dBc			-65
Phase Noise @ 100 KHz from F_0 (Below Carrier)	dBc/Hz		-100	-97
Frequency Drift over Temperature	MHz			40
Pulling Figure (12 dB Return Loss)	MHz			1
Pushing Figure, $\pm 0.2V$ Supply	MHz			10
Positive Supply Voltage	V	7.8	8	8.2
Positive Supply Current	mA			125
Tuning Port Input Capacitance	pf		12	
Dimensions	Inches		1.180" x 0.950" x 0.400"	

Typical Performance Curves @ +25°C

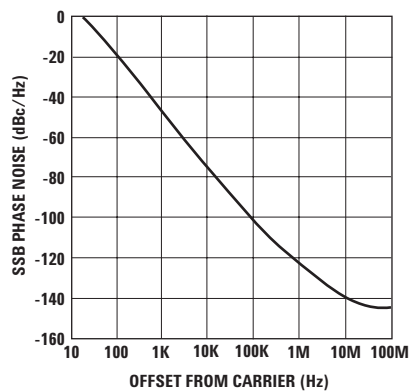


Figure 1. Typical Phase Noise Performance.

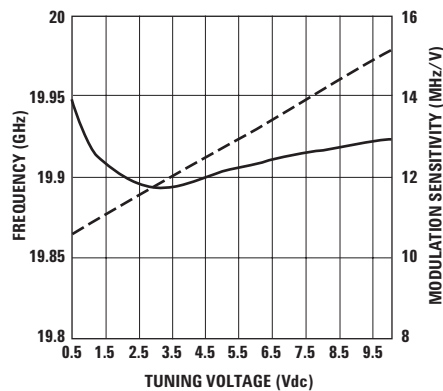


Figure 2. Frequency and Modulation Sensitivity vs. Tuning Voltage.

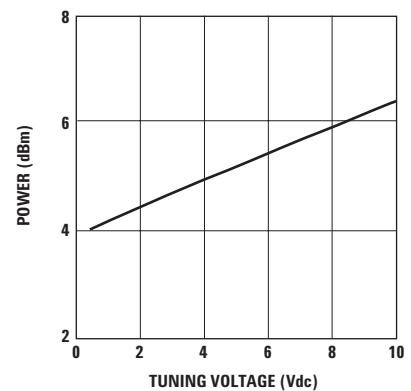


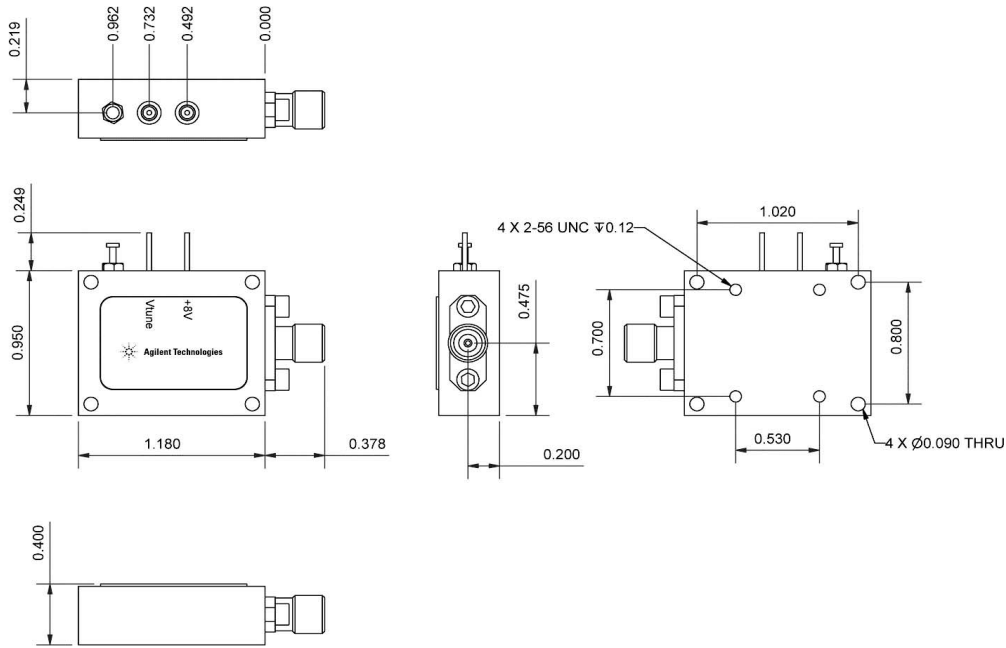
Figure 3. Power Output.

Ordering Information

Part Number

VTO-1990-SMA	SONET/SDH 19.906 GHz
VTO-2150-SMA	FEC 21.509 GHz

Package Drawing and Mechanical Dimensions (inches)



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For product information and a complete list of distributors, please go to our web site.

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Data subject to change.

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